

L Number	Hits	Search Text	DB	Time stamp
11	2	((US-20040051146-\$ or US-5811856-\$).did.) and parasitic adj bjt and resistor and (guardring guard adj ring)	USPAT; US-PGPUB	2004/10/26 14:57
12	1	((US-20040051146-\$ or US-5811856-\$).did.) and finger and bjt and bipolar	USPAT; US-PGPUB	2004/10/26 14:57
13	2	((US-20040051146-\$ or US-5811856-\$).did.) and parasitic adj bjt and bjt and bipolar	USPAT; US-PGPUB	2004/10/26 14:57
14	5170	((257/173,174,355-358,360-363) or (361/56,58,111)).CCLS.	USPAT; US-PGPUB	2004/10/26 14:58
15	41	((257/173,174,355-358,360-363) or (361/56,58,111)).CCLS.) and parasitic adj bjt	USPAT; US-PGPUB	2004/10/26 14:58
17	581	((257/173,174,355-358,360-363) or (361/56,58,111)).CCLS.) and parasitic adj (bjt or bipolar or transistor)	USPAT; US-PGPUB	2004/10/26 14:58
18	3	((5,912,494") or ("5,438,005") or ("5,223,737")).PN.	USPAT; US-PGPUB	2004/10/26 14:58
24	348	((esd electrostatic adj discharge) and feedback) and (finger multifinger)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/26 14:58
16	22	((257/173,174,355-358,360-363) or (361/56,58,111)).CCLS.) and parasitic adj bjt) and (guardring guard-ring guard adj ring ring)	USPAT; US-PGPUB	2004/10/26 14:59
19	2	((5,912,494") or ("5,438,005") or ("5,223,737")).PN.) not (((257/173,174,355-358,360-363) or (361/56,58,111)).CCLS.) and parasitic adj (bjt or bipolar or transistor))	USPAT; US-PGPUB	2004/10/26 14:59
20	20	((257/173,174,355-358,360-363) or (361/56,58,111)).CCLS.) and parasitic adj bjt) and finger	USPAT; US-PGPUB	2004/10/26 14:59
21	2	((257/173,174,355-358,360-363) or (361/56,58,111)).CCLS.) and parasitic adj bjt) and finger not (((257/173,174,355-358,360-363) or (361/56,58,111)).CCLS.) and parasitic adj bjt) and (guardring guard-ring guard adj ring ring))	USPAT; US-PGPUB	2004/10/26 14:59
22	11	((5811856") or ("5852541") or ("5949634") or ("5982217") or ("6072219") or ("6140687") or ("6249410") or ("6399990") or ("6465768") or ("6465848") or ("20040051146")).PN. or ((2002/0153570) or (2002/0163009)).CCLS.	USPAT; US-PGPUB	2004/10/26 14:59
23	1832	(esd electrostatic adj discharge) and feedback	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/26 15:01
25	240	((esd electrostatic adj discharge) and feedback) and (finger multifinger)) and (bjt parasitic transistor bipolar)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/26 15:01
26	105	((esd electrostatic adj discharge) and feedback) and (finger multifinger)) and (bjt parasitic transistor bipolar)) and (bjt parasitic transistor bipolar) with (source or emitter) with (base body)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/26 15:01
27	70	((esd electrostatic adj discharge) and feedback) and (finger multifinger)) and (bjt parasitic transistor bipolar)) and (bjt parasitic transistor bipolar) with (source or emitter) with (base body) and @pd>19930615	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/26 15:01
28	212	(esd electrostatic adj discharge) and feedback near6 (source emitter)	USPAT; US-PGPUB	2004/10/26 15:01
29	212	(esd electrostatic adj discharge) and feedback near6 (source emitter)	USPAT; US-PGPUB	2004/10/26 15:01
30	2	(esd electrostatic adj discharge) and feedback near6 (source emitter)	EPO; JPO; DERWENT; IBM_TDB	2004/10/26 15:01
31	6	879626.ap.	USPAT; US-PGPUB	2004/10/26 15:01
32	2	"879626" and ((esd electrostatic adj discharge) and feedback near6 (source emitter))	USPAT; US-PGPUB	2004/10/26 15:01

33	10	(US-5811856-\$ or US-5428498-\$ or US-5532901-\$ or US-5623156-\$ or US-6072219-\$ or US-6399990-\$ or US-6091594-\$ or US-5473169-\$).did. or (US-20020033507-\$ or US-20040105201-\$).did.	USPAT; US-PGPUB	2004/10/26 15:01
34	5	((US-5811856-\$ or US-5428498-\$ or US-5532901-\$ or US-5623156-\$ or US-6072219-\$ or US-6399990-\$ or US-6091594-\$ or US-5473169-\$).did. or (US-20020033507-\$ or US-20040105201-\$).did.) and (guardring guard-ring guard adj ring ring)	USPAT; US-PGPUB	2004/10/26 15:01
35	1	(US-20020033507-\$).did. and resistor	US-PGPUB	2004/10/26 15:01